

isc Silicon NPN Power Transistor

2SD2066

DESCRIPTION

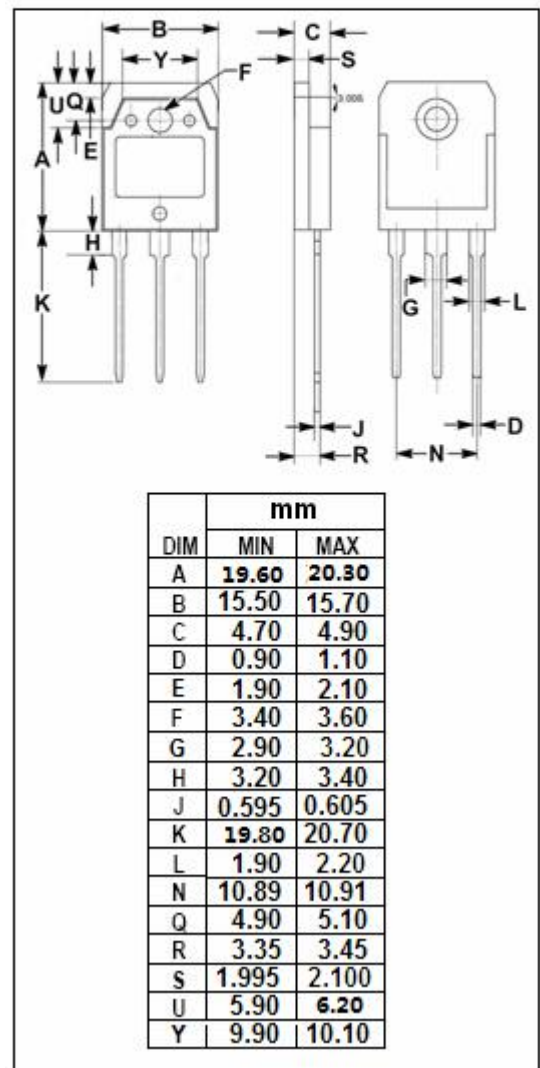
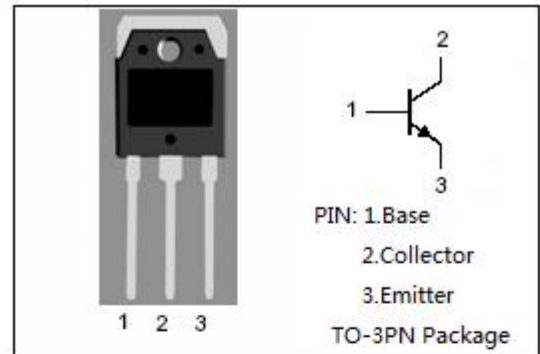
- High Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = 160V(\text{Min})$
- Good Linearity of h_{FE}
- High transition frequency(f_T)
- Wide area of safety operation
- Complement to Type 2SB1373
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Designed for high power amplifier and general purpose applications.

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	160	V
V_{CEO}	Collector-Emitter Voltage	160	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	12	A
I_{CM}	Collector Current-Peak	20	A
P_C	Collector Power Dissipation @ $T_C = 25^\circ\text{C}$	120	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^\circ\text{C}$



isc Silicon NPN Power Transistor**2SD2066****ELECTRICAL CHARACTERISTICS****T_C=25℃ unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	160			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 8A; I _B = 0.8A			2.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 8A ; V _{CE} = 5V			1.8	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 160V; I _E = 0			50	μ A
I _{EBO}	Emitter Cutoff Current	V _{EB} = 3V; I _C = 0			50	μ A
h _{FE-1}	DC Current Gain	I _C = 20mA; V _{CE} = 5V	20			
h _{FE-2}	DC Current Gain	I _C = 1A; V _{CE} = 5V	60		200	
h _{FE-3}	DC Current Gain	I _C = 8A; V _{CE} = 5V	20			
C _{OB}	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		210		pF
f _T	Current-Gain—Bandwidth Product	I _C = 0.5A ; V _{CE} = 5V		20		MHz

◆ h_{FE-2}Classifications

Q	S	P
60-120	80-160	100-200

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